

UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020

Solderable per MIL-STD-202, Method 208 @

Weight: 0.0009 grams (Approximate)

Terminals: Finish — NiPdAu

or GND

Case Material: Molded Plastic, "Green" Molding Compound.

Product Summary

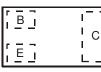
Part Number	R1 (NOM)	R2 (NOM)	Marking
DDTA114YLP	10kΩ	47kΩ	P3

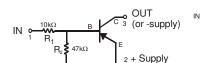
Features

- Epitaxial Planar Die Construction
- Ultra-Small Leadless Surface Mount Package
- Ideally Suited for Automated Assembly Processes
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

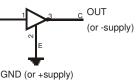
X1-DFN1006-3







Mechanical Data
Case: X1-DFN1006-3



Bottom View

Top View Pin-Out

Device Symbol

Equivalent Inverter Circuit

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DDTA114YLP-7	P3	7	8	3,000
DDTA114YLP-7B	P3	7	8	10,000

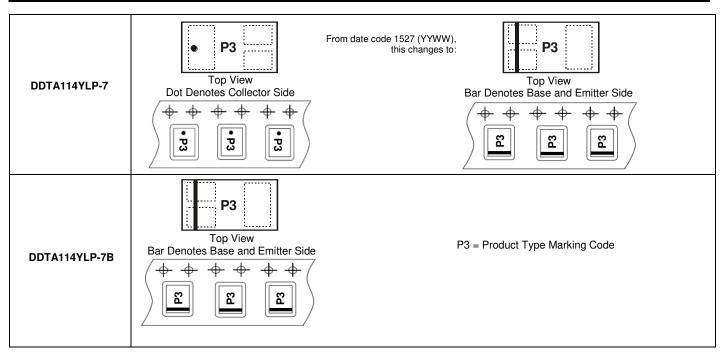
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{CC}	-50	V
Input Voltage	V _{IN}	+6 to -40	V
Output Current	lo	-70	mA
Output (Collector) Current	I _{C(MAX)}	-100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	250	mW
Power Derating above +25°C	P _{der}	2	mW/°C
Thermal Resistance, Junction to Ambient Air (Note 5) (Equivalent to one heated junction of PNP)	R _{0JA}	500	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	C°

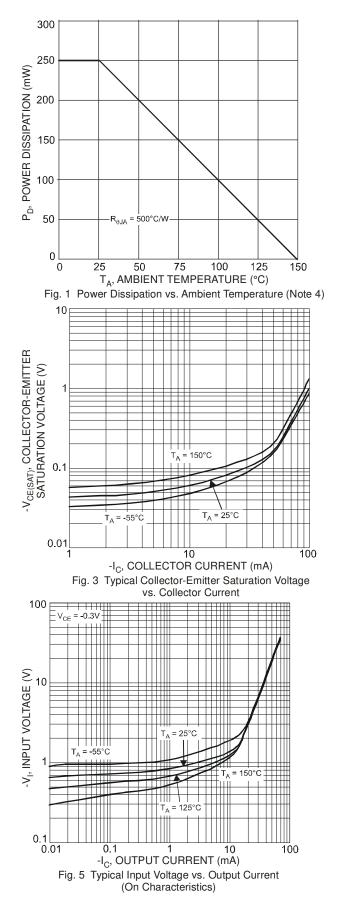
Electrical Characteristics: Discrete PNP Transistor (Q1) (@TA = +25°C, unless otherwise specified.)

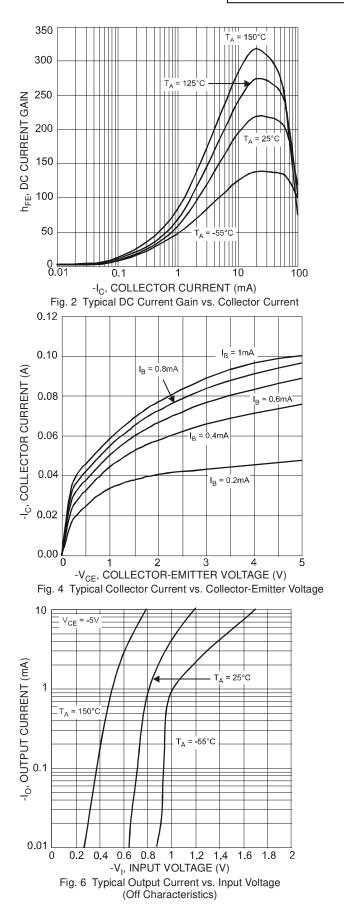
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Off Characteristics (Note 6)						
Collector-Base Breakdown Voltage	BV _{CBO}	-50	_		V	$I_{\rm C} = -100\mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	-50		_	V	$I_{\rm C} = -10.0 {\rm mA}, I_{\rm B} = 0$
Collector-Base Cut Off Current	I _{CBO}	—		-0.1	μA	$V_{CB} = -50V, I_E = 0$
Collector-Emitter Cut Off Current, I _{O(off)}	ICES	_	_	-0.1	μA	$V_{CB} = -50V, I_B = 0$
Emitter-Base Cut Off Current	I _{EBO}	_	_	-0.2	mA	$V_{EB} = 5V, I_{C} = 0$
Input Off Voltage	V _{I(off)}	-0.3			V	V _{CC} = -5V, I _O = -100µA
On Characteristics (Note 6)						
Input-On Voltage	V _{I(on)}	_		-1.4	V	$V_{O} = -0.3V, I_{O} = I_{C} = 1mA$
Input Current	h	_	_	-0.88	mA	$V_1 = -5V$
DC Current Gain	h _{FE}	80	_	_	_	$V_{CE} = -5V, I_{C} = -5mA$
Collector-Emitter Saturation Voltage	V _{CE(sat)}	—		-0.25	V	I _C = -50mA, I _B = -2.5mA
Output On Voltage (Same as V _{CE(sat)})	V _{O(on)}	_	-0.1	-0.3	V	I _I = -0.25mA, I _O = -5mA
Input Resistance	R1	7	10	13	kΩ	_
Resistance Ratio	(R2/R1)	3.7	4.7	5.7	_	_
Small Signal Characteristics	•	•				•
Current Gain-Bandwidth Product	f _T	_	250		MHz	V _{CE} = -10V, I _E = -5mA, f = 100 MHz

5. For the device mounted on minimum recommended pad layout 102 copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink. 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%. Notes:







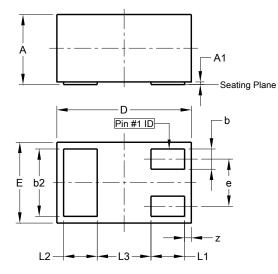


DDTA114YLP Document number: DS30807 Rev. 7 - 2



Package Outline Dimensions

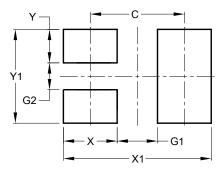
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X1-DFN1006-3				
Dim	Min	Max	Тур	
Α	0.47	0.53	0.50	
A1	0.00	0.05	0.03	
b	0.10	0.20	0.15	
b2	0.45	0.55	0.50	
D	0.95	1.075	1.00	
Е	0.55	0.675	0.60	
е	-	-	0.35	
L1	0.20	0.30	0.25	
L2	0.20	0.30	0.25	
L3	-	-	0.40	
Z	0.02	0.08	0.05	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Ŷ	0.25
Y1	0.70



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